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Low Offset Voltage Dual Comparators

The LM393 series are dual independent precision voltage comparators capable of single or split supply operation. These devices are designed to permit a common mode range—to—ground level with single supply operation. Input offset voltage specifications as low as 2.0 mV make this device an excellent selection for many applications in consumer, automotive, and industrial electronics.

Features

- Wide Single-Supply Range: 2.0 Vdc to 36 Vdc
- Split–Supply Range: ±1.0 Vdc to ±18 Vdc
- Very Low Current Drain Independent of Supply Voltage: 0.4 mA
- Low Input Bias Current: 25 nA
- Low Input Offset Current: 5.0 nA
- Low Input Offset Voltage: 5.0 mV (max) LM293/393
- Input Common Mode Range to Ground Level
- Differential Input Voltage Range Equal to Power Supply Voltage
- Output Voltage Compatible with DTL, ECL, TTL, MOS, and CMOS Logic Levels
- ESD Clamps on the Inputs Increase the Ruggedness of the Device without Affecting Performance
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

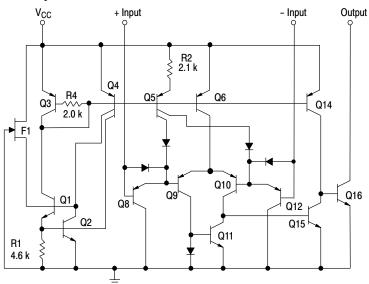


Figure 1. Representative Schematic Diagram (Diagram shown is for 1 comparator)

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PDIP-8 N SUFFIX CASE 626

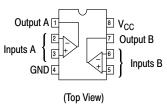


SOIC-8 D SUFFIX CASE 751



Micro8™ DM SUFFIX CASE 846A

PIN CONNECTIONS



DEVICE MARKING AND ORDERING INFORMATION

See detailed marking information and ordering and shipping information on pages 6 and 7 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	+36 or ±18	V
Input Differential Voltage	V _{IDR}	36	V
Input Common Mode Voltage Range	V _{ICR}	-0.3 to +36	V
Output Voltage	V _O	36	V
Output Short Circuit-to-Ground Output Sink Current (Note 1)	I _{SC} I _{Sink}	Continuous 20	mA
Power Dissipation @ T _A = 25°C Derate above 25°C	P _D 1/R _{θJA}	570 5.7	mW mW/°C
Operating Ambient Temperature Range LM293 LM393, LM393E LM2903, LM2903E LM2903V, NCV2903 (Note 2)	T _A	-25 to +85 0 to +70 -40 to +105 -40 to +125	Ô
Maximum Operating Junction Temperature LM393, LM393E, LM2903, LM2903E, LM2903V LM293, NCV2903	T _{J(max)}	150 150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ESD RATINGS

Rating	НВМ	ММ	Unit
ESD Protection at any Pin (Human Body Model – HBM, Machine Model – MM)			
NCV2903 (Note 2)	2000	200	V
LM393E, LM2903E	1500	150	V
LM393DG/DR2G, LM2903DG/DR2G	250	100	V
All Other Devices	1500	150	V

The maximum output current may be as high as 20 mA, independent of the magnitude of V_{CC}, output short circuits to V_{CC} can cause excessive heating and eventual destruction.
 NCV2903 is qualified for automotive use.

ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0 \text{ Vdc}$, $T_{low} \le T_A \le T_{high}$, unless otherwise noted.)

		LM29	93, LM39	3, LM393E	LM2903/E/V, NCV2903			
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage (Note 4)	V _{IO}							mV
$T_A = 25$ °C		-	±1.0	±5.0	-	±2.0	±7.0	
$T_{low} \le T_A \le T_{high}$		-	_	±9.0	-	±9.0	±15	
Input Offset Current	I _{IO}							nA
$T_{A} = 25^{\circ}C$		_	±5.0	±50	-	±5.0	±50	
$T_{low} \le T_A \le T_{high}$		-	_	±150	-	±50	±200	
Input Bias Current (Note 5)	I_{IB}							nA
T _A = 25°C		_	20	250	-	20	250	
$T_{low} \le T_A \le T_{high}$		-	_	400	-	20	500	
Input Common Mode Voltage Range (Note 6)	V_{ICR}							V
T _A = 25°C		0	_	V _{CC} –1.5	0	_	V _{CC} –1.5	
$T_{low} \le T_A \le T_{high}$		0	-	V _{CC} –2.0	0	_	V _{CC} –2.0	
Voltage Gain	A_{VOL}	50	200	-	25	200	-	V/mV
$R_L \ge 15 \text{ k}\Omega$, $V_{CC} = 15 \text{ Vdc}$, $T_A = 25^{\circ}\text{C}$								
Large Signal Response Time	-	-	300	-	-	300	-	ns
V_{in} = TTL Logic Swing, V_{ref} = 1.4 Vdc								
$V_{RL} = 5.0 \text{ Vdc}, R_L = 5.1 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$								
Response Time (Note 7)	t _{TLH}	-	1.3	-	-	1.5	-	μS
$V_{RL} = 5.0 \text{ Vdc}, R_L = 5.1 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$								
Input Differential Voltage (Note 8)	V_{ID}	-	_	V _{CC}	-	-	V _{CC}	V
All $V_{in} \ge GND$ or $V-$ Supply (if used)								
Output Sink Current	I _{Sink}	6.0	16	-	6.0	16	-	mA
$V_{in} \ge 1.0 \text{ Vdc}, V_{in+} = 0 \text{ Vdc}, V_O \le 1.5 \text{ Vdc } T_A = 25^{\circ}C$								
Output Saturation Voltage	V_{OL}							mV
$V_{in} \ge 1.0 \text{ Vdc}, V_{in+} = 0, I_{Sink} \le 4.0 \text{ mA}, T_A = 25^{\circ}\text{C}$		_	150	400	-	_	400	
$T_{low} \le T_A \le T_{high}$		-	_	700	-	200	700	
Output Leakage Current	I _{OL}							nA
V_{in-} = 0 V, V_{in+} \geq 1.0 Vdc, V_O = 5.0 Vdc, T_A = 25°C		-	0.1	-	_	0.1	_	
$V_{in-} = 0 \text{ V}, V_{in+} \ge 1.0 \text{ Vdc}, V_{O} = 30 \text{ Vdc},$								
$T_{low} \le T_A \le T_{high}$			_	1000	-	_	1000	
Supply Current	I _{CC}							mA
$R_L = \infty$ Both Comparators, $T_A = 25^{\circ}C$		-	0.4	1.0	-	0.4	1.0	
R _L = ∞ Both Comparators, V _{CC} = 30 V		-	_	2.5	-	-	2.5	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

 $\begin{array}{l} LM293\ T_{low} = -25^{\circ}C,\ T_{high} = +85^{\circ}C\\ LM393,\ LM393E\ T_{low} = 0^{\circ}C,\ T_{high} = +70^{\circ}C\\ LM2903,\ LM2903E\ T_{low} = -40^{\circ}C,\ T_{high} = +105^{\circ}C\\ LM2903V\ \&\ NCV2903\ T_{low} = -40^{\circ}C,\ T_{high} = +125^{\circ}C \end{array}$

NCV2903 is qualified for automotive use.

- 3. The maximum output current may be as high as 20 mA, independent of the magnitude of V_{CC}, output short circuits to V_{CC} can cause excessive heating and eventual destruction.
- 4. At output switch point, $V_O \simeq 1.4$ Vdc, $R_S = 0~\Omega$ with V_{CC} from 5.0 Vdc to 30 Vdc, and over the full input common mode range $(0 \text{ V to V}_{CC} = -1.5 \text{ V}).$
- 5. Due to the PNP transistor inputs, bias current will flow out of the inputs. This current is essentially constant, independent of the output state, therefore, no loading changes will exist on the input lines.
- 6. Input common mode of either input should not be permitted to go more than 0.3 V negative of ground or minus supply. The upper limit of common mode range is V_{CC} –1.5 V.
- 7. Response time is specified with a 100 mV step and 5.0 mV of overdrive. With larger magnitudes of overdrive faster response times are obtainable
- 8. The comparator will exhibit proper output state if one of the inputs becomes greater than V_{CC}, the other input must remain within the common mode range. The low input state must not be less than -0.3 V of ground or minus supply.

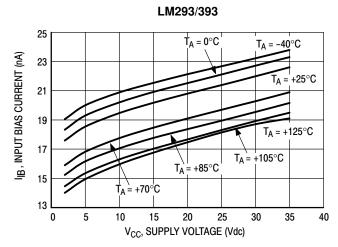


Figure 2. Input Bias Current versus
Power Supply Voltage

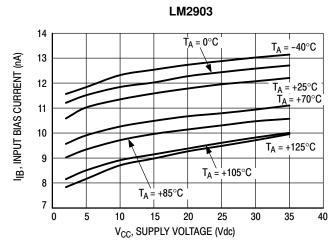


Figure 3. Input Bias Current versus Power Supply Voltage

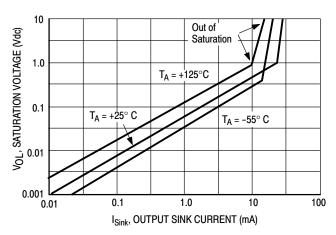


Figure 4. Output Saturation Voltage versus Output Sink Current

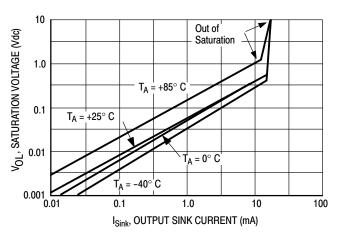


Figure 5. Output Saturation Voltage versus Output Sink Current

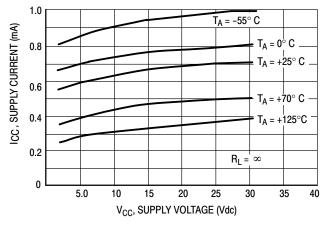


Figure 6. Power Supply Current versus Power Supply Voltage

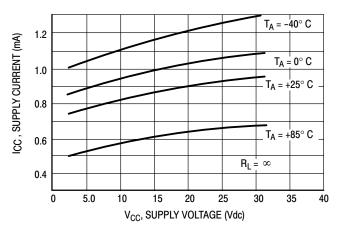
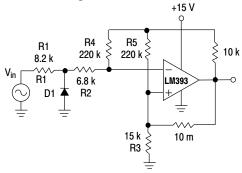


Figure 7. Power Supply Current versus Power Supply Voltage

APPLICATIONS INFORMATION

These dual comparators feature high gain, wide bandwidth characteristics. This gives the device oscillation tendencies if the outputs are capacitively coupled to the inputs via stray capacitance. This oscillation manifests itself during output transitions (V_{OL} to V_{OH}). To alleviate this situation, input resistors < 10 k Ω should be used.



D1 prevents input from going negative by more than 0.6 $\rm V.$

R1 + R2 = R3

$$13 \le \frac{R5}{48}$$
 for small error in zero crossing.

Figure 8. Zero Crossing Detector (Single Supply)

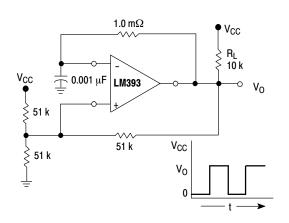
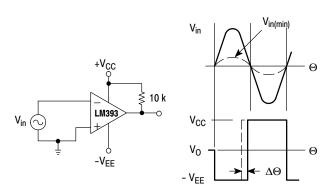


Figure 10. Free-Running Square-Wave Oscillator

The addition of positive feedback ($<10\,\mathrm{mV}$) is also recommended. It is good design practice to ground all unused pins.

Differential input voltages may be larger than supply voltage without damaging the comparator's inputs. Voltages more negative than -0.3 V should not be used.



 $V_{in(min)} \approx 0.4 \text{ V}$ peak for 1% phase distortion ($\Delta\Theta$).

Figure 9. Zero Crossing Detector (Split Supply)

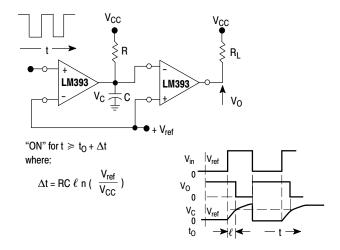


Figure 11. Time Delay Generator

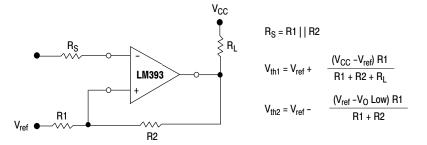
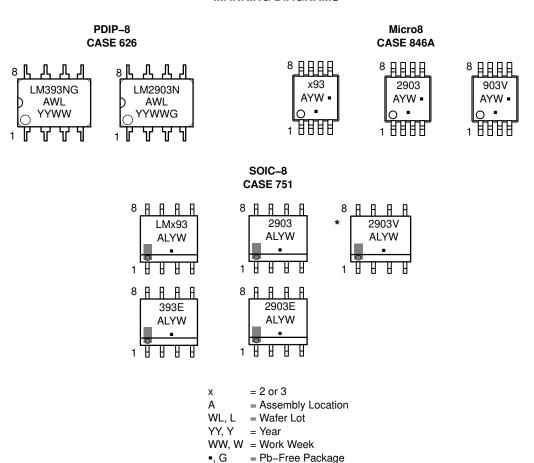


Figure 12. Comparator with Hysteresis

MARKING DIAGRAMS



(Note: Microdot may be in either location)

*This marking diagram also applies to NCV2903DR2G

ORDERING INFORMATION

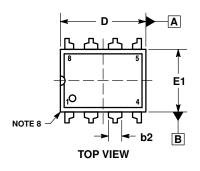
Device	Operating Temperature Range	Package	Shipping [†]
LM293DG		SOIC-8 (Pb-Free)	98 Units / Rail
LM293DR2G	-25°C to +85°C		2500 / Tape & Reel
LM293DMR2G	25 6 16 166 6	Micro8 (Pb–Free)	4000 / Tape and Reel
LM393DG		SOIC-8	98 Units / Rail
LM393DR2G		(Pb-Free)	2500 / Tape & Reel
LM393EDR2G	0°C to +70°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM393NG	0 0 10 170 0	PDIP-8 (Pb-Free)	50 Units / Rail
LM393DMR2G		Micro8 (Pb–Free)	4000 / Tape and Reel
LM2903DG		SOIC-8	98 Units / Rail
LM2903DR2G		(Pb-Free)	2500 / Tape & Reel
LM2903EDR2G	-40°C to +105°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM2903DMR2G	0 10 1.00 0	Micro8 (Pb–Free)	4000 / Tape and Reel
LM2903NG		PDIP-8 (Pb-Free)	50 Units / Rail
LM2903VDG		SOIC-8	98 Units / Rail
LM2903VDR2G		(Pb-Free)	2500 / Tape & Reel
LM2903VNG	-40°C to +125°C	PDIP-8 (Pb-Free)	50 Units / Rail
NCV2903DR2G*		SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV2903DMR2G*		Micro8 (Pb-Free)	4000 / Tape & Reel

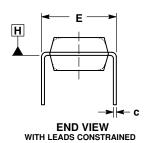
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

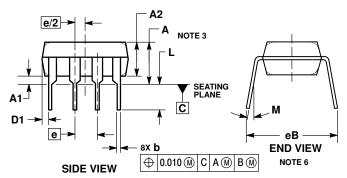
PACKAGE DIMENSIONS

PDIP-8 N, AN, VN SUFFIX CASE 626-05 **ISSUE P**





NOTE 5



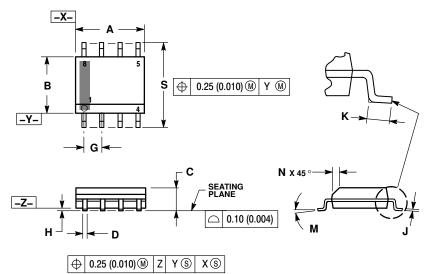
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCHES.

- 2. CONTROLLING DIMENSION: INCHES.
 3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
 4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH. NOT TO EXCEED 0.10 INCH.
 DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM
- PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
- DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE
- LEADS UNCONSTRAINED.
 DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
 PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE
- CORNERS).

	INC	HES	MILLIM	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α		0.210		5.33	
A1	0.015		0.38		
A2	0.115	0.195	2.92	4.95	
b	0.014	0.022	0.35	0.56	
b2	0.060	TYP	1.52 TYP		
С	0.008	0.014	0.20	0.36	
D	0.355	0.400	9.02	10.16	
D1	0.005		0.13		
E	0.300	0.325	7.62	8.26	
E1	0.240	0.280	6.10	7.11	
е	0.100 BSC		2.54	BSC	
eВ		0.430		10.92	
L	0.115	0.150	2.92	3.81	
М	-	10°		10°	

PACKAGE DIMENSIONS

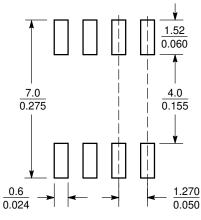
SOIC-8 NB CASE 751-07 **ISSUE AK**



- NOTES:
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 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- MAXIMUM MOLD PROTRUSION 0.15 (0.006)
 PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL
 IN EXCESS OF THE D DIMENSION AT
 MAXIMUM MATERIAL CONDITION.
 751-01 THRU 751-06 ARE OBSOLETE. NEW
 STANDARD IS 751 07
- STANDARD IS 751-07.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	1.27 BSC		0 BSC
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*

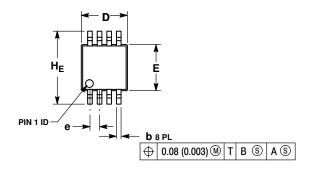


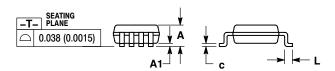
 $\left(\frac{\text{mm}}{\text{inches}}\right)$ SCALE 6:1

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

Micro8™ CASE 846A-02 **ISSUE J**



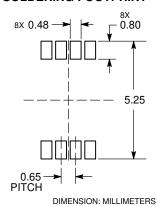


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 0.13 (0.000) PER SIJE. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- 846A-01 OBSOLETE, NEW STANDARD 846A-02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10		-	0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
С	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
е		0.65 BSC		0.026 BSC		
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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